

### PNP -2.0A -30V Middle Power Transistor

Parameter	Value
$V_{\sf CEO}$	-30V
I <sub>C</sub>	-2.0A

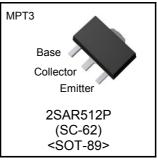
#### Features

- 1) Suitable for Middle Power Driver
- 2) Complementary NPN Types: 2SCR512P
- 3) Low V<sub>CE(sat)</sub>

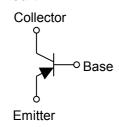
$$V_{CE(sat)} = -0.4V(Max.)$$
  
 $(I_C/I_B = -700mA/ -35mA)$ 

4) Lead Free/RoHS Compliant.

# ●Outline



#### •Inner circuit



### Applications

Motor driver , LED driver Power supply

### Packaging specifications

Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
2SAR512P	MPT3	4540	T100	180	12	1,000	MB

### ● Absolute maximum ratings (Ta = 25°C)

Parameter		Symbol	Values	Unit
Collector-base voltage		V <sub>CBO</sub>	-30	V
Collector-emitter voltage		$V_{CEO}$	-30	V
Emitter-base voltage	Emitter-base voltage		-6	V
Collector current	DC	I <sub>C</sub>	-2.0	А
	Pulsed	I <sub>CP</sub> *1	-4.0	А
Power dissipation		P <sub>D</sub> *2	0.5	W
		P <sub>D</sub> *3	2.0	W
Junction temperature		T <sub>j</sub>	150	°C
Range of storage temperature		T <sub>stg</sub>	−55 to +150	°C

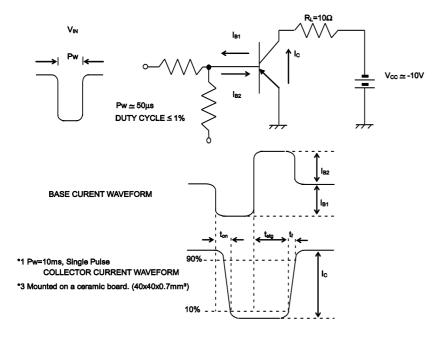
- \*1 Pw=10ms, single pulse
- \*2 Each terminal mounted on a reference land
- \*3 Mounted on a ceramic board (40×40×0.7mm)

### ●Electrical characteristics(Ta = 25°C)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector-emitter breakdown voltage	BV <sub>CEO</sub>	I <sub>C</sub> = -1mA	-30	-	-	V
Collector-base breakdown voltage	BV <sub>CBO</sub>	$I_{C} = -100 \mu A$	-30	-	-	V
Emitter-base breakdown voltage	BV <sub>EBO</sub>	$I_E = -100 \mu A$	-6	ı	ı	V
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> = -30V	ı	ı	-1	μА
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> = -4V	-	-	-1	μА
Collector-emitter saturation voltage	V <sub>CE(sat)</sub> *1	$I_C = -700 \text{mA}, I_B = -35 \text{mA}$	-	-0.20	-0.40	V
DC current gain	h <sub>FE</sub>	$V_{CE} = -2V, I_{C} = -100 \text{mA}$	200	-	500	-
Transition frequency	f <sub>⊤</sub>	$V_{CE} = -10V, I_{E} = -100 \text{mA}$ f=100MHz	-	430	-	MHz
Output capacitance	C <sub>ob</sub>	$V_{CB} = -10V, I_{E} = 0A,$ f = 1MHz	-	15	-	pF
Turn-on time	t <sub>on</sub> *2	I <sub>C</sub> = -1A	-	30	-	ns
Storage time	t <sub>stg</sub> *2	I <sub>B1</sub> = –100mA I <sub>B2</sub> =100mA	1	170	-	ns
Fall time	t <sub>f</sub> *2	V <sub>CC</sub> ≃ −10V	-	15	-	ns

<sup>\*1</sup> Pulsed

## •Switching time test circuit



<sup>\*2</sup> See switching time test circuit

### ●Electrical characteristic curves(Ta = 25°C)

Fig.1 Ground Emitter Propagation Characteristics

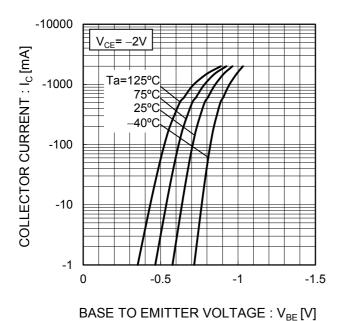
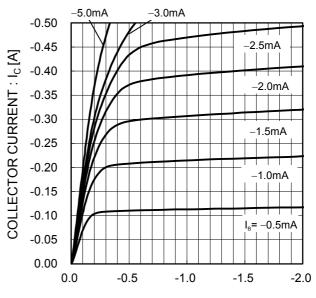


Fig.2 Typical Output Characteristics



COLECTOR TO EMITTE VOLTAGE :  $V_{CE}[V]$ 

Fig.3 DC Current Gain vs. Collector Current(I)

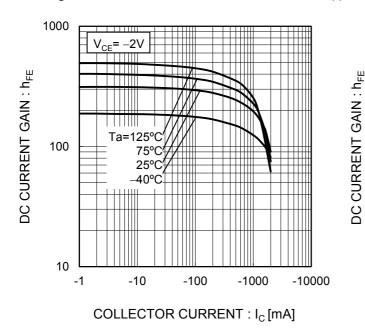
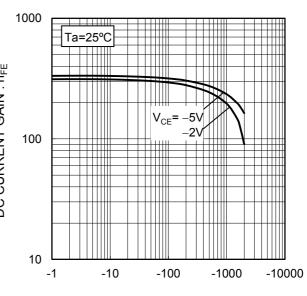
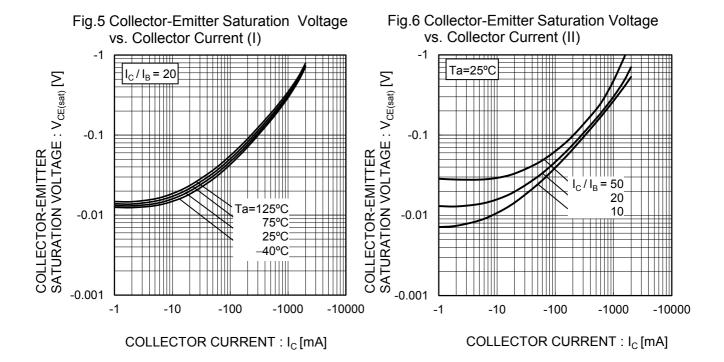


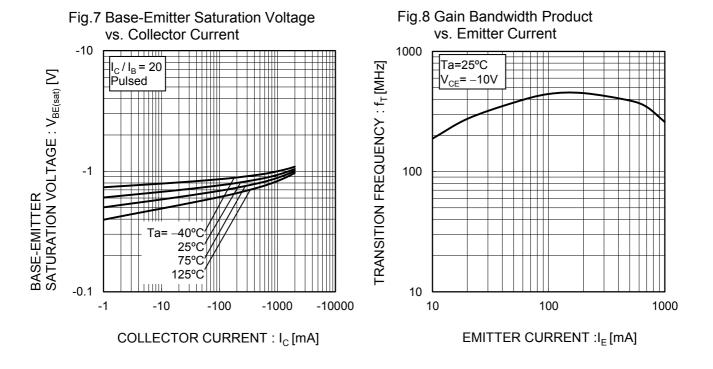
Fig.4 DC current gain vs. output current (II)



COLLECTOR CURRENT : I<sub>C</sub> [mA]

### ●Electrical characteristic curves(Ta = 25°C)





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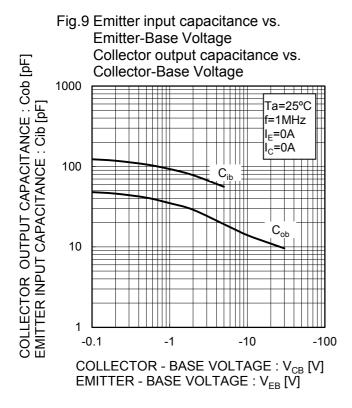
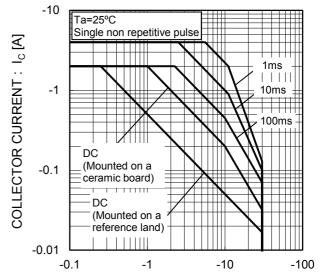
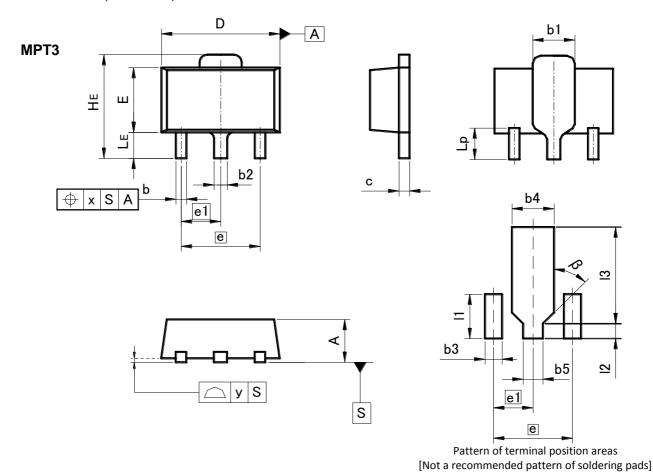


Fig.10 Safe Operating Area



COLLECTOR TO EMITTER VOLTAGE: V<sub>CE</sub> [V]

### ●Dimensions (Unit: mm)



	MILIM	ETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	1.40	1.50	0.055	0.059	
b	0.30	0.50	0.012	0.020	
b1	1.50	1.70	0.059	0.067	
b2	0.40	0.60	0.016	0.024	
С	0.35	0.50	0.014	0.020	
D	4.40	4.70	0.173	0.185	
Е	2.40	2.70	0.094	0.106	
е	3.00		0.118		
e1	1.	50	0.0	59	
HE	3.70	4.30	0.146	0.169	
LE	0.80	1.20	0.031	0.047	
Lp	1.01	1.41	0.040	0.056	
Х	_	0.15	_	0.006	
У	_	0.10	_	0.004	

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
b3	-	0.65	-	0.026
b4	ı	1.70	-	0.067
b5	ı	0.75	-	0.030
11	ı	1.71	I	0.067
12	ı	0.58	I	0.023
13	-	3.72	-	0.146
β	45°		45	0

Dimension in mm / inches

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